E · / Fattice Semiconductor Corporation - <u>LCMXO3L-6900C-6BG256I Datasheet</u>



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The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details

Product Status	Active
Number of LABs/CLBs	858
Number of Logic Elements/Cells	6864
Total RAM Bits	245760
Number of I/O	206
Number of Gates	-
Voltage - Supply	2.375V ~ 3.465V
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 100°C (TJ)
Package / Case	256-LFBGA
Supplier Device Package	256-CABGA (14x14)
Purchase URL	https://www.e-xfl.com/product-detail/lattice-semiconductor/lcmxo3I-6900c-6bg256i

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MachXO3 Family Data Sheet Architecture

February 2017

Advance Data Sheet DS1047

Architecture Overview

The MachXO3L/LF family architecture contains an array of logic blocks surrounded by Programmable I/O (PIO). All logic density devices in this family have sysCLOCK[™] PLLs and blocks of sysMEM Embedded Block RAM (EBRs). Figure 2-1 and Figure 2-2 show the block diagrams of the various family members.





Notes:

MachXO3L/LF-640 is similar to MachXO3L/LF-1300. MachXO3L/LF-640 has a lower LUT count.

MachXO3L devices have NVCM, MachXO3LF devices have Flash.

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This phase shift can be either programmed during configuration or can be adjusted dynamically. In dynamic mode, the PLL may lose lock after a phase adjustment on the output used as the feedback source and not relock until the $t_{I,OCK}$ parameter has been satisfied.

The MachXO3L/LF also has a feature that allows the user to select between two different reference clock sources dynamically. This feature is implemented using the PLLREFCS primitive. The timing parameters for the PLL are shown in the sysCLOCK PLL Timing table.

The MachXO3L/LF PLL contains a WISHBONE port feature that allows the PLL settings, including divider values, to be dynamically changed from the user logic. When using this feature the EFB block must also be instantiated in the design to allow access to the WISHBONE ports. Similar to the dynamic phase adjustment, when PLL settings are updated through the WISHBONE port the PLL may lose lock and not relock until the t_{LOCK} parameter has been satisfied. The timing parameters for the PLL are shown in the sysCLOCK PLL Timing table.

For more details on the PLL and the WISHBONE interface, see TN1282, MachXO3 sysCLOCK PLL Design and Usage Guide.



Figure 2-7. PLL Diagram

Table 2-4 provides signal descriptions of the PLL block.

Table 2-4	. PLL	Signal	Descriptions
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Port Name	I/O	Description	
CLKI	Ι	Input clock to PLL	
CLKFB	I	Feedback clock	
PHASESEL[1:0]	Ι	Select which output is affected by Dynamic Phase adjustment ports	
PHASEDIR	I	Dynamic Phase adjustment direction	
PHASESTEP	Ι	Dynamic Phase step – toggle shifts VCO phase adjust by one step.	



Table 2-12. Supported Output Standards

Output Standard	V _{CCIO} (Typ.)
Single-Ended Interfaces	
LVTTL	3.3
LVCMOS33	3.3
LVCMOS25	2.5
LVCMOS18	1.8
LVCMOS15	1.5
LVCMOS12	1.2
LVCMOS33, Open Drain	_
LVCMOS25, Open Drain	_
LVCMOS18, Open Drain	—
LVCMOS15, Open Drain	_
LVCMOS12, Open Drain	_
PCI33	3.3
Differential Interfaces	
LVDS ¹	2.5, 3.3
BLVDS, MLVDS, RSDS 1	2.5
LVPECL ¹	3.3
MIPI ¹	2.5
LVTTLD	3.3
LVCMOS33D	3.3
LVCMOS25D	2.5
LVCMOS18D	1.8

1. These interfaces can be emulated with external resistors in all devices.

sysIO Buffer Banks

The numbers of banks vary between the devices of this family. MachXO3L/LF-1300 in the 256 Ball packages and the MachXO3L/LF-2100 and higher density devices have six I/O banks (one bank on the top, right and bottom side and three banks on the left side). The MachXO3L/LF-1300 and lower density devices have four banks (one bank per side). Figures 2-15 and 2-16 show the sysIO banks and their associated supplies for all devices.



Figure 2-18. PC Core Block Diagram



Table 2-14 describes the signals interfacing with the I²C cores.

 Table 2-14. PC Core Signal Description

Signal Name	I/O	Description
i2c_scl	Bi-directional	Bi-directional clock line of the I ² C core. The signal is an output if the I ² C core is in master mode. The signal is an input if the I ² C core is in slave mode. MUST be routed directly to the pre-assigned I/O of the chip. Refer to the Pinout Information section of this document for detailed pad and pin locations of I ² C ports in each MachXO3L/LF device.
i2c_sda	Bi-directional	Bi-directional data line of the l^2C core. The signal is an output when data is transmitted from the l^2C core. The signal is an input when data is received into the l^2C core. MUST be routed directly to the pre-assigned I/O of the chip. Refer to the Pinout Information section of this document for detailed pad and pin locations of l^2C ports in each MachXO3L/LF device.
i2c_irqo	Output	Interrupt request output signal of the I ² C core. The intended usage of this signal is for it to be connected to the WISHBONE master controller (i.e. a microcontroller or state machine) and request an interrupt when a specific condition is met. These conditions are described with the I ² C register definitions.
cfg_wake	Output	Wake-up signal – To be connected only to the power module of the MachXO3L/LF device. The signal is enabled only if the "Wakeup Enable" feature has been set within the EFB GUI, I^2C Tab.
cfg_stdby	Output	Stand-by signal – To be connected only to the power module of the MachXO3L/LF device. The signal is enabled only if the "Wakeup Enable" feature has been set within the EFB GUI, I^2C Tab.

Hardened SPI IP Core

Every MachXO3L/LF device has a hard SPI IP core that can be configured as a SPI master or slave. When the IP core is configured as a master it will be able to control other SPI enabled chips connected to the SPI bus. When the core is configured as the slave, the device will be able to interface to an external SPI master. The SPI IP core on MachXO3L/LF devices supports the following functions:

- Configurable Master and Slave modes
- Full-Duplex data transfer
- Mode fault error flag with CPU interrupt capability
- Double-buffered data register
- Serial clock with programmable polarity and phase
- LSB First or MSB First Data Transfer
- Interface to custom logic through 8-bit WISHBONE interface



Table 2-17. MachXO3L/LF Power Saving Features Description

Device Subsystem	Feature Description
Bandgap	The bandgap can be turned off in standby mode. When the Bandgap is turned off, analog circuitry such as the POR, PLLs, on-chip oscillator, and differential I/O buffers are also turned off. Bandgap can only be turned off for 1.2 V devices.
Power-On-Reset (POR)	The POR can be turned off in standby mode. This monitors VCC levels. In the event of unsafe V_{CC} drops, this circuit reconfigures the device. When the POR circuitry is turned off, limited power detector circuitry is still active. This option is only recommended for applications in which the power supply rails are reliable.
On-Chip Oscillator	The on-chip oscillator has two power saving features. It may be switched off if it is not needed in your design. It can also be turned off in Standby mode.
PLL	Similar to the on-chip oscillator, the PLL also has two power saving features. It can be statically switched off if it is not needed in a design. It can also be turned off in Standby mode. The PLL will wait until all output clocks from the PLL are driven low before powering off.
I/O Bank Controller	Differential I/O buffers (used to implement standards such as LVDS) consume more than ratioed single-ended I/Os such as LVCMOS and LVTTL. The I/O bank controller allows the user to turn these I/Os off dynamically on a per bank selection.
Dynamic Clock Enable for Primary Clock Nets	Each primary clock net can be dynamically disabled to save power.
Power Guard	Power Guard is a feature implemented in input buffers. This feature allows users to switch off the input buffer when it is not needed. This feature can be used in both clock and data paths. Its biggest impact is that in the standby mode it can be used to switch off clock inputs that are distributed using general routing resources.

For more details on the standby mode refer to TN1289, Power Estimation and Management for MachXO3 Devices.

Power On Reset

MachXO3L/LF devices have power-on reset circuitry to monitor V_{CCINT} and V_{CCIO} voltage levels during power-up and operation. At power-up, the POR circuitry monitors V_{CCINT} and V_{CCIO} (controls configuration) voltage levels. It then triggers download from the on-chip configuration NVCM/Flash memory after reaching the V_{PORUP} level specified in the Power-On-Reset Voltage table in the DC and Switching Characteristics section of this data sheet. For "E" devices without voltage regulators, V_{CCINT} is the same as the V_{CC} supply voltage. For "C" devices with voltage regulators, V_{CCINT} is regulated from the V_{CC} supply voltage. From this voltage reference, the time taken for configuration and entry into user mode is specified as NVCM/Flash Download Time ($t_{REFRESH}$) in the DC and Switching Characteristics section of this data sheet. Before and during configuration. Note that for "C" devices, a separate POR circuit monitors external V_{CC} voltage in addition to the POR circuit that monitors the internal post-regulated power supply voltage level.

Once the device enters into user mode, the POR circuitry can optionally continue to monitor V_{CCINT} levels. If V_{CCINT} drops below $V_{PORDNBG}$ level (with the bandgap circuitry switched on) or below $V_{PORDNSRAM}$ level (with the bandgap circuitry switched off to conserve power) device functionality cannot be guaranteed. In such a situation the POR issues a reset and begins monitoring the V_{CCINT} and V_{CCIO} voltage levels. $V_{PORDNBG}$ and $V_{PORDNSRAM}$ are both specified in the Power-On-Reset Voltage table in the DC and Switching Characteristics section of this data sheet.

Note that once an "E" device enters user mode, users can switch off the bandgap to conserve power. When the bandgap circuitry is switched off, the POR circuitry also shuts down. The device is designed such that a mini-mal, low power POR circuit is still operational (this corresponds to the $V_{PORDNSRAM}$ reset point described in the paragraph above). However this circuit is not as accurate as the one that operates when the bandgap is switched on. The low power POR circuit emulates an SRAM cell and is biased to trip before the vast majority of SRAM cells flip. If users are concerned about the V_{CC} supply dropping below V_{CC} (min) they should not shut down the bandgap or POR circuit.



TraceID

Each MachXO3L/LF device contains a unique (per device), TraceID that can be used for tracking purposes or for IP security applications. The TraceID is 64 bits long. Eight out of 64 bits are user-programmable, the remaining 56 bits are factory-programmed. The TraceID is accessible through the EFB WISHBONE interface and can also be accessed through the SPI, I²C, or JTAG interfaces.

Density Shifting

The MachXO3L/LF family has been designed to enable density migration within the same package. Furthermore, the architecture ensures a high success rate when performing design migration from lower density devices to higher density devices. In many cases, it is also possible to shift a lower utilization design targeted for a high-density device to a lower density device. However, the exact details of the final resource utilization will impact the likely success in each case. When migrating from lower to higher density or higher to lower density, ensure to review all the power supplies and NC pins of the chosen devices. For more details refer to the MachXO3 migration files.



MachXO3 Family Data Sheet DC and Switching Characteristics

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Absolute Maximum Ratings^{1, 2, 3}

	MachXO3L/LF E (1.2 V)	MachXO3L/LF C (2.5 V/3.3 V)
Supply Voltage V _{CC}	\ldots .–0.5 V to 1.32 V \ldots \ldots	–0.5 V to 3.75 V
Output Supply Voltage V _{CCIO}	–0.5 V to 3.75 V	–0.5 V to 3.75 V
I/O Tri-state Voltage Applied ^{4, 5}	–0.5 V to 3.75 V	–0.5 V to 3.75 V
Dedicated Input Voltage Applied ⁴	–0.5 V to 3.75 V	–0.5 V to 3.75 V
Storage Temperature (Ambient)	–55 °C to 125 °C	–55 °C to 125 °C
Junction Temperature (T ₁)	–40 °C to 125 °C	–40 °C to 125 °C

1. Stress above those listed under the "Absolute Maximum Ratings" may cause permanent damage to the device. Functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

2. Compliance with the Lattice Thermal Management document is required.

3. All voltages referenced to GND.

4. Overshoot and undershoot of -2 V to (V_{IHMAX} + 2) volts is permitted for a duration of <20 ns.

5. The dual function I^2C pins SCL and SDA are limited to -0.25 V to 3.75 V or to -0.3 V with a duration of <20 ns.

Recommended Operating Conditions¹

Symbol	Parameter		Max.	Units
V _{CC} ¹	Core Supply Voltage for 1.2 V Devices	1.14	1.26	V
	Core Supply Voltage for 2.5 V/3.3 V Devices	2.375	3.465	V
V _{CCIO} ^{1, 2, 3}	I/O Driver Supply Voltage		3.465	V
t _{JCOM}	Junction Temperature Commercial Operation		85	°C
t _{JIND}	Junction Temperature Industrial Operation	-40	100	°C

1. Like power supplies must be tied together. For example, if V_{CCIO} and V_{CC} are both the same voltage, they must also be the same supply.

2. See recommended voltages by I/O standard in subsequent table.

3. V_{CCIO} pins of unused I/O banks should be connected to the V_{CC} power supply on boards.

Power Supply Ramp Rates¹

	iyp.	wax.	Units
t _{RAMP} Power supply ramp rates for all power supplies. 0.01	—	100	V/ms

1. Assumes monotonic ramp rates.

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Static Supply Current – C/E Devices^{1, 2, 3, 6}

Symbol	Parameter	Device	Typ.⁴	Units
I _{CC}	Core Power Supply	LCMXO3L/LF-1300C 256 Ball Package	4.8	mA
		LCMXO3L/LF-2100C	4.8	mA
		LCMXO3L/LF-2100C 324 Ball Package	8.45	mA
		LCMXO3L/LF-4300C	8.45	mA
		LCMXO3L/LF-4300C 400 Ball Package	12.87	mA
		LCMXO3L/LF-6900C ⁷	12.87	mA
		LCMXO3L/LF-9400C ⁷	17.86	mA
		LCMXO3L/LF-640E	1.00	mA
		LCMXO3L/LF-1300E	1.00	mA
		LCMXO3L/LF-1300E 256 Ball Package	1.39	mA
		LCMXO3L/LF-2100E	1.39	mA
		LCMXO3L/LF-2100E 324 Ball Package	2.55	mA
		LCMXO3L/LF-4300E	2.55	mA
		LCMXO3L/LF-6900E	4.06	mA
		LCMXO3L/LF-9400E	5.66	mA
I _{CCIO}	Bank Power Supply ⁵ VCCIO = 2.5 V	All devices	0	mA

1. For further information on supply current, please refer to TN1289, Power Estimation and Management for MachXO3 Devices.

2. Assumes blank pattern with the following characteristics: all outputs are tri-stated, all inputs are configured as LVCMOS and held at V_{CCIO} or GND, on-chip oscillator is off, on-chip PLL is off.

3. Frequency = 0 MHz.

4. $T_J = 25$ °C, power supplies at nominal voltage.

5. Does not include pull-up/pull-down.

6. To determine the MachXO3L/LF peak start-up current data, use the Power Calculator tool.

7. Determination of safe ambient operating conditions requires use of the Diamond Power Calculator tool.



Programming and Erase Supply Current – C/E Devices^{1, 2, 3, 4}

Symbol	Parameter	Device	Typ.⁴	Units
I _{CC}	Core Power Supply	LCMXO3L/LF-1300C 256 Ball Package	22.1	mA
		LCMXO3L/LF-2100C	22.1	mA
		LCMXO3L/LF-2100C 324 Ball Package	26.8	mA
		LCMXO3L/LF-4300C	26.8	mA
		LCMXO3L/LF-4300C 400 Ball Package	33.2	mA
		LCMXO3L/LF-6900C	33.2	mA
		LCMXO3L/LF-9400C	39.6	mA
		LCMXO3L/LF-640E	17.7	mA
		LCMXO3L/LF-1300E	17.7	mA
		LCMXO3L/LF-1300E 256 Ball Package	18.3	mA
		LCMXO3L/LF-2100E	18.3	mA
		LCMXO3L/LF-2100E 324 Ball Package	20.4	mA
		LCMXO3L/LF-4300E	20.4	mA
		LCMXO3L/LF-6900E	23.9	mA
		LCMXO3L/LF-9400E	28.5	mA
I _{CCIO}	Bank Power Supply ⁵ VCCIO = 2.5 V	All devices	0	mA

1. For further information on supply current, please refer to TN1289, Power Estimation and Management for MachXO3 Devices.

2. Assumes all inputs are held at $V_{\mbox{\scriptsize CCIO}}$ or GND and all outputs are tri-stated.

3. Typical user pattern.

4. JTAG programming is at 25 MHz.

5. $T_J = 25$ °C, power supplies at nominal voltage.

6. Per bank. $V_{CCIO} = 2.5$ V. Does not include pull-up/pull-down.



sysIO Differential Electrical Characteristics

The LVDS differential output buffers are available on the top side of the MachXO3L/LF PLD family.

LVDS

Parameter Symbol	Parameter Description	Test Conditions	Min.	Тур.	Max.	Units
V _{INP} V _{INM}	Input Voltage	V _{CCIO} = 3.3 V	0	_	2.605	V
		V _{CCIO} = 2.5 V	0	_	2.05	V
V _{THD}	Differential Input Threshold		±100	_		mV
V	Input Common Mode Voltage	V _{CCIO} = 3.3 V	0.05	_	2.6	V
VCM	input Common Mode Voltage	V _{CCIO} = 2.5 V	0.05	_	2.0	V
I _{IN}	Input current	Power on	_	_	±10	μA
V _{OH}	Output high voltage for V_{OP} or V_{OM}	R _T = 100 Ohm	_	1.375	_	V
V _{OL}	Output low voltage for V_{OP} or V_{OM}	R _T = 100 Ohm	0.90	1.025	_	V
V _{OD}	Output voltage differential	(V _{OP} - V _{OM}), R _T = 100 Ohm	250	350	450	mV
ΔV_{OD}	Change in V _{OD} between high and low		_	_	50	mV
V _{OS}	Output voltage offset	(V _{OP} - V _{OM})/2, R _T = 100 Ohm	1.125	1.20	1.395	V
ΔV_{OS}	Change in V _{OS} between H and L		—	—	50	mV
IOSD	Output short circuit current	V _{OD} = 0 V driver outputs shorted	_	_	24	mA

Over Recommended Operating Conditions



BLVDS

The MachXO3L/LF family supports the BLVDS standard through emulation. The output is emulated using complementary LVCMOS outputs in conjunction with resistors across the driver outputs. The input standard is supported by the LVDS differential input buffer. BLVDS is intended for use when multi-drop and bi-directional multi-point differential signaling is required. The scheme shown in Figure 3-2 is one possible solution for bi-directional multi-point differential signals.

Figure 3-2. BLVDS Multi-point Output Example



Table 3-2. BLVDS DC Conditions¹

Over Recommended	Operating	Conditions
	operating	Contaitions

			Nominal			
Symbol	Description	Zo = 45	Zo = 90	Units		
Z _{OUT}	Output impedance	20	20	Ohms		
R _S	Driver series resistance	80	80	Ohms		
R _{TLEFT}	R _{TLEFT} Left end termination		90	Ohms		
R _{TRIGHT}	Right end termination	45	90	Ohms		
V _{OH}	Output high voltage		1.480	V		
V _{OL}	Output low voltage		1.020	V		
V _{OD}	Output differential voltage	0.253	0.459	V		
V _{CM}	Output common mode voltage	1.250	1.250	V		
I _{DC}	DC output current	11.236	10.204	mA		

1. For input buffer, see LVDS table.



Maximum sysIO Buffer Performance

I/O Standard	Max. Speed	Units
MIPI	450	MHz
LVDS25	400	MHz
LVDS25E	150	MHz
BLVDS25	150	MHz
BLVDS25E	150	MHz
MLVDS25	150	MHz
MLVDS25E	150	MHz
LVPECL33	150	MHz
LVPECL33E	150	MHz
LVTTL33	150	MHz
LVTTL33D	150	MHz
LVCMOS33	150	MHz
LVCMOS33D	150	MHz
LVCMOS25	150	MHz
LVCMOS25D	150	MHz
LVCMOS18	150	MHz
LVCMOS18D	150	MHz
LVCMOS15	150	MHz
LVCMOS15D	150	MHz
LVCMOS12	91	MHz
LVCMOS12D	91	MHz



DC and Switching Characteristics MachXO3 Family Data Sheet

		-6		-5		
Description	Description Device			Min.	Max.	Units
Generic DDRX4 Outputs with Clock and Data Centered at Pin Using PCLK Pin for Clock Input – GDDRX4_TX.ECLK.Centered ^{8, 9}						
Output Data Valid Before CLK Output		0.455		0.570		ns
Output Data Valid After CLK Output		0.455	—	0.570	_	ns
DDRX4 Serial Output Data Speed	MachXO3L/LF devices,	—	800	—	630	Mbps
DDRX4 ECLK Frequency (minimum limited by PLL)	top side only	_	400	_	315	MHz
SCLK Frequency	-		100		79	MHz
Itputs – GDDR71_TX.ECLK.7:1 ^{8, 9}						
Output Data Invalid Before CLK Output			0.160	_	0.180	ns
Output Data Invalid After CLK Output			0.160		0.180	ns
DDR71 Serial Output Data Speed	MachXO3L/LF devices,		756		630	Mbps
DDR71 ECLK Frequency	top side only	_	378	—	315	MHz
7:1 Output Clock Frequency (SCLK) (mini- mum limited by PLL)		_	108	_	90	MHz
MIPI D-PHY Outputs with Clock and Data Centered at Pin Using PCLK Pin for Clock Input - GDDRX4_TX.ECLK.Centered ^{10, 11, 12}						
Output Data Valid Before CLK Output		0.200	—	0.200	_	UI
Output Data Valid After CLK Output		0.200	—	0.200	_	UI
MIPI D-PHY Output Data Speed	All MachXO3L/LF	_	900	—	900	Mbps
MIPI D-PHY ECLK Frequency (minimum limited by PLL)	devices, top side only	_	450	_	450	MHz
SCLK Frequency	<u> </u>	—	112.5	—	112.5	MHz
	Description RX4 Outputs with Clock and Data Centered CECLK.Centered ^{8, 9} Output Data Valid Before CLK Output Output Data Valid After CLK Output DDRX4 Serial Output Data Speed DDRX4 ECLK Frequency (minimum limited by PLL) SCLK Frequency ttputs – GDDR71_TX.ECLK.7:1 ^{8, 9} Output Data Invalid Before CLK Output Output Data Invalid After CLK Output DDR71 Serial Output Data Speed DDR71 ECLK Frequency 7:1 Output Clock Frequency (SCLK) (mini- mum limited by PLL) Outputs with Clock and Data Centered at P C.ECLK.Centered ^{10, 11, 12} Output Data Valid Before CLK Output Output Data Valid After CLK Output MIPI D-PHY Output Data Speed MIPI D-PHY ECLK Frequency (minimum limited by PLL) SCLK Frequency	DescriptionDeviceRX4 Outputs with Clock and Data Centered at Pin Using PCLK Pin for C.ECLK.Centered ^{8, 9} In Using PCLK Pin for C.ECLK.Centered ^{8, 9} Output Data Valid Before CLK OutputMachXO3L/LF devices, top side onlyDDRX4 Serial Output Data SpeedMachXO3L/LF devices, top side onlyDDRX4 ECLK Frequency (minimum limited by PLL)MachXO3L/LF devices, top side onlySCLK FrequencyOutput Data Invalid Before CLK OutputOutput Data Invalid After CLK OutputMachXO3L/LF devices, top side onlyOutput Data Invalid After CLK OutputMachXO3L/LF devices, top side onlyDDR71 Serial Output Data SpeedMachXO3L/LF devices, top side onlyDDR71 ECLK Frequency 7:1 Output Clock Frequency (SCLK) (mini- mum limited by PLL)MachXO3L/LF devices, top side onlyOutput Data Valid Before CLK OutputOutput Data Valid Before CLK OutputOutput Data Valid Before CLK OutputAll MachXO3L/LF devices, top side onlyOutput Data Valid After CLK OutputAll MachXO3L/LF devices, top side onlyMIPI D-PHY Output Data SpeedAll MachXO3L/LF devices, top side onlyMIPI D-PHY ECLK Frequency (minimum limited by PLL)All MachXO3L/LF devices, top side onlySCLK FrequencyAll MachXO3L/LF devices, top side only	Description Device Min. RX4 Outputs with Clock and Data Centered at Pin Using PCLK Pin for Clock (LECLK.Centered ^{8,9}) 0.455 Output Data Valid Before CLK Output 0.455 DDRX4 Serial Output Data Speed MachXO3L/LF devices, top side only DDRX4 ECLK Frequency (minimum limited by PLL) MachXO3L/LF devices, top side only SCLK Frequency Output Data Invalid Before CLK Output Output Data Invalid Before CLK Output Output Data Invalid Before CLK Output Output Data Invalid After CLK Output DDR71 Serial Output Data Speed MachXO3L/LF devices, top side only DDR71 ECLK Frequency Output Clock Frequency (SCLK) (minimum limited by PLL) Output Data Valid After CLK Output Output Data Valid Before CLK Output Output Data Valid After CLK Output 0.200 0.200 0.200 Output Data Valid After CLK Out	-6Min.Max.RX4 Outputs with Clock and Data Centered at Pin Using PCLK Pin for Clock Input - CLECLK.Centered ^{8, 9} Output Data Valid Before CLK Output0.455Output Data Valid After CLK OutputMachXO3L/LF devices, top side only0.455DDRX4 ECLK Frequency (minimum limited by PLL)MachXO3L/LF devices, top side only800SCLK Frequency (minimum limited by PLL)100400Output Data Invalid Before CLK Output0.160Output Data Invalid After CLK Output0.160DDR71 Serial Output Data Speed DDR71 Serial Output Data SpeedMachXO3L/LF devices, top side only108Output Swith Clock and Data Centered at Pin Using PCLK Pin for Clock Input - t.ECLK.Centered ^{10, 11, 12} 0.200Output Data Valid Before CLK Output DDR71 Serial Output Data SpeedAll MachXO3L/LF devices, top side only0.200Output Data Valid After CLK Output Mup PLL)All MachXO3L/LF devices, top side only0.200MIPI D-PHY Output Data Speed MIPI D-PHY CLK Frequency (minimum limited by PLL)All MachXO3L/LF devices, top side only450MIPI D-PHY ECLK Frequency (minimum limited by PLL)450450	Description Image: Description Image: Description Max. Min. Max. Min. RX4 Outputs with Clock and Data Centered at Pin Using PCLK Pin for Clock Input - LECLK.Centered ^{8, 9} 0.455 - 0.570 Output Data Valid Before CLK Output MachXO3L/LF devices, top side only 0.455 - 0.570 DDRX4 Serial Output Data Speed MachXO3L/LF devices, top side only - 800 - DDRX4 ECLK Frequency (minimum limited by PLL) MachXO3L/LF devices, top side only - 400 - SCLK Frequency - 0.160 -	Description Device Min. Max. Min. Max. RX4 Outputs with Clock and Data Centered at Pin Using PCLK Pin for Clock Input - LECLK.Centered ^{9,9} 0.455 - 0.570 - Output Data Valid Before CLK Output MachXO3L/LF devices, top side only 0.455 - 0.570 - DDRX4 Serial Output Data Speed MachXO3L/LF devices, top side only 0.455 - 0.570 - DDRX4 ECLK Frequency (minimum limited by PLL) MachXO3L/LF devices, top side only - 800 - 630 SCLK Frequency - 0.160 - 916 - 916 Output Data Invalid Before CLK Output MachXO3L/LF devices, top side only - 0.160 - 0.180 DDR71 ECLK Frequency MachXO3L/LF devices, top side only - 756 - 630 DDR71 ECLK Frequency MachXO3L/LF devices, top side only - 756 - 630 DDR71 ECLK Frequency MachXO3L/LF devices, top side only - 108 - 90 Output Data Valid After CLK Output MachXO3L/LF

1. Exact performance may vary with device and design implementation. Commercial timing numbers are shown at 85 °C and 1.14 V. Other operating conditions, including industrial, can be extracted from the Diamond software.

2. General I/O timing numbers based on LVCMOS 2.5, 8 mA, 0pf load, fast slew rate.

3. Generic DDR timing numbers based on LVDS I/O (for input, output, and clock ports).

4. 7:1 LVDS (GDDR71) uses the LVDS I/O standard (for input, output, and clock ports).

5. For Generic DDRX1 mode $t_{SU} = t_{HO} = (t_{DVE} - t_{DVA} - 0.03 \text{ ns})/2$.

6. The t_{SU DEL} and t_{H DEL} values use the SCLK_ZERHOLD default step size. Each step is 105 ps (-6), 113 ps (-5), 120 ps (-4).

7. This number for general purpose usage. Duty cycle tolerance is +/-10%.

8. Duty cycle is $\pm -5\%$ for system usage.

9. Performance is calculated with 0.225 UI.

10. Performance is calculated with 0.20 UI.

11. Performance for Industrial devices are only supported with VCC between 1.16 V to 1.24 V.

12. Performance for Industrial devices and -5 devices are not modeled in the Diamond design tool.

13. The above timing numbers are generated using the Diamond design tool. Exact performance may vary with the device selected.

14. Above 800 Mbps is only supported with WLCSP and csfBGA packages

15. Between 800 Mbps to 900 Mbps:

a. VIDTH exceeds the MIPI D-PHY Input DC Conditions Table 3-4 and can be calculated with the equation tSU or tH = -0.0005*VIDTH + 0.3284

b. Example calculations

i. tSU and tHO = 0.28 with VIDTH = 100 mV

ii. tSU and tHO = 0.25 with VIDTH = 170 mV

iii. tSU and tHO = 0.20 with VIDTH = 270 mV



Figure 3-6. Receiver GDDR71_RX. Waveforms



Figure 3-7. Transmitter GDDR71_TX. Waveforms





JTAG Port Timing Specifications

Symbol	Parameter	Min.	Max.	Units
f _{MAX}	TCK clock frequency	—	25	MHz
t _{BTCPH}	TCK [BSCAN] clock pulse width high	20	—	ns
t _{BTCPL}	TCK [BSCAN] clock pulse width low	20	—	ns
t _{BTS}	TCK [BSCAN] setup time	10	—	ns
t _{BTH}	TCK [BSCAN] hold time	8	—	ns
t _{BTCO}	TAP controller falling edge of clock to valid output	—	10	ns
t _{BTCODIS}	TAP controller falling edge of clock to valid disable	—	10	ns
t _{BTCOEN}	TAP controller falling edge of clock to valid enable		10	ns
t _{BTCRS}	BSCAN test capture register setup time		—	ns
t _{BTCRH}	BSCAN test capture register hold time	20	—	ns
t _{BUTCO}	O BSCAN test update register, falling edge of clock to valid output		25	ns
t _{BTUODIS}	BSCAN test update register, falling edge of clock to valid disable	—	25	ns
t _{BTUPOEN}	BSCAN test update register, falling edge of clock to valid enable	—	25	ns

Figure 3-8. JTAG Port Timing Waveforms





sysCONFIG Port Timing Specifications

Symbol	Parameter		Min.	Max.	Units
All Configuration Mo	odes				
t _{PRGM}	PROGRAMN low p	ulse accept	55	_	ns
t _{PRGMJ}	PROGRAMN low p	ulse rejection	_	25	ns
t _{INITL}	INITN low time	LCMXO3L/LF-640/ LCMXO3L/LF-1300	—	55	us
		LCMXO3L/LF-1300 256-Ball Package/ LCMXO3L/LF-2100	_	70	us
		LCMXO3L/LF-2100 324-Ball Package/ LCMXO3-4300	_	105	us
		LCMXO3L/LF-4300 400-Ball Package/ LCMXO3-6900	_	130	us
		LCMXO3L/LF-9400C	_	175	us
t _{DPPINIT}	PROGRAMN low to	INITN low	_	150	ns
t _{DPPDONE}	PROGRAMN low to	DONE low	_	150	ns
t _{IODISS}	PROGRAMN low to	o I/O disable	_	120	ns
Slave SPI					
f _{MAX}	CCLK clock frequer	CCLK clock frequency			MHz
t _{CCLKH}	CCLK clock pulse v	CCLK clock pulse width high			ns
t _{CCLKL}	CCLK clock pulse v	vidth low	7.5	_	ns
t _{STSU}	CCLK setup time		2	_	ns
t _{STH}	CCLK hold time		0	_	ns
t _{STCO}	CCLK falling edge t	to valid output	—	10	ns
t _{STOZ}	CCLK falling edge t	to valid disable	_	10	ns
t _{STOV}	CCLK falling edge t	to valid enable	_	10	ns
t _{SCS}	Chip select high tim	ne	25	—	ns
t _{SCSS}	Chip select setup ti	me	3	—	ns
t _{SCSH}	Chip select hold tim	ne	3	_	ns
Master SPI				•	
f _{MAX}	MCLK clock freque	ncy	—	133	MHz
t _{MCLKH}	MCLK clock pulse v	width high	3.75	—	ns
t _{MCLKL}	MCLK clock pulse v	width low	3.75	—	ns
t _{STSU}	MCLK setup time		5	—	ns
t _{STH}	MCLK hold time		1	—	ns
t _{CSSPI}	INITN high to chip s	select low	100	200	ns
t _{MCI K}	INITN high to first N	/ICLK edge	0.75	1	us



	MachXO3L/LF-2100					
	WLCSP49	CSFBGA121	CSFBGA256	CSFBGA324	CABGA256	CABGA324
General Purpose IO per Bank		•	•			•
Bank 0	19	24	50	71	50	71
Bank 1	0	26	52	62	52	68
Bank 2	13	26	52	72	52	72
Bank 3	0	7	16	22	16	24
Bank 4	0	7	16	14	16	16
Bank 5	6	10	20	27	20	28
Total General Purpose Single Ended IO	38	100	206	268	206	279
Differential IO per Bank						
Bank 0	10	12	25	36	25	36
Bank 1	0	13	26	30	26	34
Bank 2	6	13	26	36	26	36
Bank 3	0	3	8	10	8	12
Bank 4	0	3	8	6	8	8
Bank 5	3	5	10	13	10	14
Total General Purpose Differential IO	19	49	103	131	103	140
Dual Function IO	25	33	33	37	33	37
Number 7:1 or 8:1 Gearboxes						•
Number of 7:1 or 8:1 Output Gearbox Available (Bank 0)	5	7	14	18	14	18
Number of 7:1 or 8:1 Input Gearbox Available (Bank 2)	6	13	14	18	14	18
High-speed Differential Outputs						•
Bank 0	5	7	14	18	14	18
VCCIO Pins		•	•			•
Bank 0	2	1	4	4	4	4
Bank 1	0	1	3	4	4	4
Bank 2	1	1	4	4	4	4
Bank 3	0	1	2	2	1	2
Bank 4	0	1	2	2	2	2
Bank 5	1	1	2	2	1	2
VCC	2	4	8	8	8	10
GND	4	10	24	16	24	16
NC	0	0	0	13	1	0
Reserved for Configuration	1	1	1	1	1	1
Total Count of Bonded Pins	49	121	256	324	256	324



	MachXO3L/LF-4300						
	WLCSP81	CSFBGA121	CSFBGA256	CSFBGA324	CABGA256	CABGA324	CABGA400
General Purpose IO per Bank							
Bank 0	29	24	50	71	50	71	83
Bank 1	0	26	52	62	52	68	84
Bank 2	20	26	52	72	52	72	84
Bank 3	7	7	16	22	16	24	28
Bank 4	0	7	16	14	16	16	24
Bank 5	7	10	20	27	20	28	32
Total General Purpose Single Ended IO	63	100	206	268	206	279	335
Differential IO per Bank							
Bank 0	15	12	25	36	25	36	42
Bank 1	0	13	26	30	26	34	42
Bank 2	10	13	26	36	26	36	42
Bank 3	3	3	8	10	8	12	14
Bank 4	0	3	8	6	8	8	12
Bank 5	3	5	10	13	10	14	16
Total General Purpose Differential IO	31	49	103	131	103	140	168
Dual Function IO	25	37	37	37	37	37	37
Number 7:1 or 8:1 Gearboxes							
Number of 7:1 or 8:1 Output Gearbox Available (Bank 0)	10	7	18	18	18	18	21
Number of 7:1 or 8:1 Input Gearbox Available (Bank 2)	10	13	18	18	18	18	21
High-speed Differential Outputs							
Bank 0	10	7	18	18	18	18	21
VCCIO Pins							
Bank 0	3	1	4	4	4	4	5
Bank 1	0	1	3	4	4	4	5
Bank 2	2	1	4	4	4	4	5
Bank 3	1	1	2	2	1	2	2
Bank 4	0	1	2	2	2	2	2
Bank 5	1	1	2	2	1	2	2
VCC	4	4	8	8	8	10	10
GND	6	10	24	16	24	16	33
NC	0	0	0	13	1	0	0
Reserved for Configuration	1	1	1	1	1	1	1
Total Count of Bonded Pins	81	121	256	324	256	324	400



	MachXO3L/LF-9400C					
	CSFBGA256	CABGA256	CABGA400	CABGA484		
General Purpose IO per Bank	•					
Bank 0	50	50	83	95		
Bank 1	52	52	84	96		
Bank 2	52	52	84	96		
Bank 3	16	16	28	36		
Bank 4	16	16	24	24		
Bank 5	20	20	32	36		
Total General Purpose Single Ended IO	206	206	335	383		
Differential IO per Bank	·					
Bank 0	25	25	42	48		
Bank 1	26	26	42	48		
Bank 2	26	26	42	48		
Bank 3	8	8	14	18		
Bank 4	8	8	12	12		
Bank 5	10	10	16	18		
Total General Purpose Differential IO	103	103	168	192		
Dual Function IO	37	37	37	45		
Number 7:1 or 8:1 Gearboxes	•					
Number of 7:1 or 8:1 Output Gearbox Available (Bank 0)	20	20	22	24		
Number of 7:1 or 8:1 Input Gearbox Available (Bank 2)	20	20	22	24		
High-speed Differential Outputs	•					
Bank 0	20	20	21	24		
VCCIO Pins	·					
Bank 0	4	4	5	9		
Bank 1	3	4	5	9		
Bank 2	4	4	5	9		
Bank 3	2	1	2	3		
Bank 4	2	2	2	3		
Bank 5	2	1	2	3		
VCC	8	8	10	12		
GND	24	24	33	52		
NC	0	1	0	0		
Reserved for Configuration	1	1	1	1		
Total Count of Bonded Pins	256	256	400	484		





Date	Version	Section	Change Summary
June 2014	1.0	—	Product name/trademark adjustment.
		Introduction	Updated Features section.
			Updated Table 1-1, MachXO3L Family Selection Guide. Changed fcCSP packages to csfBGA. Adjusted 121-ball csfBGA arrow.
			Introduction section general update.
		Architecture	General update.
		DC and Switching Characteristics	Updated sysIO Recommended Operating Conditions section. Removed V _{REF} (V) column. Added standards.
			Updated Maximum sysIO Buffer Performance section. Added MIPI I/O standard.
			Updated MIPI D-PHY Emulation section. Changed Low Speed to Low Power. Updated Table 3-4, MIPI DC Conditions.
			Updated Table 3-5, MIPI D-PHY Output DC Conditions.
			Updated Maximum sysIO Buffer Performance section.
			Updated MachXO3L External Switching Characteristics – C/E Device section.
May 2014	00.3	Introduction	Updated Features section.
			Updated Table 1-1, MachXO3L Family Selection Guide. Moved 121-ball fcCSP arrow.
			General update of Introduction section.
		Architecture	General update.
		Pinout Information	Updated Pin Information Summary section. Updated or added data on WLCSP49, WLCSP81, CABGA324, and CABGA400 for specific devices.
		Ordering Information	Updated MachXO3L Part Number Description section. Updated or added data on WLCSP49, WLCSP81, CABGA324, and CABGA400 for specific devices.
			Updated Ultra Low Power Commercial and Industrial Grade Devices, Halogen Free (RoHS) Packaging section. Added part numbers.
February 2014	00.2	DC and Switching Characteristics	Updated MachXO3L External Switching Characteristics – C/E Devices table. Removed LPDDR and DDR2 parameters.
	00.1	_	Initial release.